

CAT32C101

1K-Bit SERIAL E2PROM

FEATURES

- Low Power CMOS Technology
- 2.2 to 3.5V Operation
- 64 x 16 or 128 x 8 Selectable Serial Memory
- Self-Timed Write Cycle with Auto-Clear
- 1.9V Read Operation

- Hardware and Software Write Protection
- Power-Up Inadvertant Write Protection
- 100,000 Program/Erase Cycles
- 100 Year Data Retention
- Optional High Endurance Device Available

DESCRIPTION

The CAT32C101 is a 1K bit Serial E²PROM memory device which can be configured as either 64 registers by 16 bits (ORG pin at V_{CC)} or 128 registers by 8 bits (ORG pin at GND). Each register can be written (or read) serially by using the DI (or DO) pin. The CAT32C101 is

manufactured using Catalyst's advanced CMOS E²PROM floating gate technology. It is designed to endure 100,000 program/erase cycles and has a data retention of 100 years. The device is available in 8 pin DIP or SO packages.

PIN CONFIGURATION

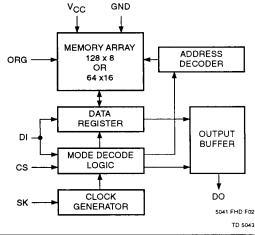
DIP Package			SO Package J			so	SO Package K		
cs □•1	$ abla_{\mathbb{F}}$	⊐ vcc	ис Ц	•1 8	ORG	cs 🖽	•1 8	b vcc	
SK 🗖 2	7	□ NC	Vcc 더	2 7	GND	sk ⊏	2 7	□ NC	
DI 🖂 3	6	ORG	cs 🗗	3 6	DO [미다	3 6	ORG	
DO 🗆 4	5	□ GND	sk ぱ	4 5		DO [4 5	GND	
			L,		1			1	5041 FHD F01

PIN FUNCTIONS

Pin Name	Function					
cs	Chip Select					
SK	Clock Input					
DI	Serial Data Input					
DO	Serial Data Output					
V _{CC}	+2.2V to +3.5V Power Supply					
GND	Ground					
NC	No Connection					
ORG	Memory Organization					

Note: When the ORG pin is connected to V_{CC} , the 64 x 16 organization is selected. When it is connected to ground, the 128 x 8 organization is selected. If the ORG pin is left unconnected, then an internal pullup device will select the 64 x 16 organization.

BLOCK DIAGRAM



Characteristics subject to change without notice

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ABSOLUTE MAXIMUM RATINGS*

Temperature Under Bias55°C to +125°C
Storage Temperature65°C to +150°C
Voltage on any Pin with Respect to Ground ⁽¹⁾ 2.0V to +V _{CC} +2.0V
V _{CC} with Respect to Ground2.0V to +7.0V
Package Power Dissipation Capability (Ta = 25°C)
Lead Soldering Temperature (10 secs)300°C
Output Short Circuit Current ⁽²⁾ 100 mA

*COMMENT

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions outside of those listed in the operational sections of this specification is not implied. Exposure to any absolute maximum rating for extended periods may affect device performance and reliability.

RELIABILITY CHARACTERISTICS

Symbol	Parameter	Min.	Max.	Units	Reference Test Method
N _{END} (3)	Endurance	100,000		Cycles/Byte	MIL-STD-883, Test Method 1033
T _{DR} (3)	Data Retention	100		Years	MIL-STD-883, Test Method 1008
V _{ZAP} ⁽³⁾	ESD Susceptibility	2000		Volts	MIL-STD-883, Test Method 3015
I _{LTH} (3)(4)	Latch-Up	100		mA	JEDEC Standard 17

D.C. OPERATING CHARACTERISTICS

CAT32C101 T_A= 0°C to +70°C, V_{CC} = +2.2V to +3.5V, unless otherwise specified.

			Limits			Test Conditions	
Symbol	Parameter	Min.	Тур.	Max.	Units		
Icc1	Power Supply Current (Operating)			2	mA	DI = 0.0V, SK = 3.5V V _{CC} = 3.5V, CS = 3.5V, Output Open	
ICC2	Power Supply Current (Standby)			2	μА	V _{CC} = 3.5V, CS = 0V DI = 0V SK = 0V ORG = 3.5V	
l _{LI}	Input Leakage Current			2	μА	V _{IN} = 0V to 3.5V	
lLO	Output Leakage Current (Including ORG Pin)			10	μА	V _{OUT} = 0V to 3.5V, CS = 0V	
V _{IH}	High Level Input Voltage	V _{CC} - 0.3		V _{CC} + 1	V		
VIL	Low Level Input Voltage	-0.1		0.3	V		
Voн	High Level Output Voltage	V _{CC} - 0.3			V	l _{OH} = -10μA	
VoL	Low Level Output Voltage		-	0.3	V	l _{OL} = 10μA	

Note:

⁽¹⁾ The minimum DC input voltage is -0.5V. During transitions, inputs may undershoot to -2.0V for periods of less than 20 ns. Maximum DC voltage on output pins is V_{CC} +0.5V, which may overshoot to V_{CC} +2.0V for periods of less than 20 ns.

⁽²⁾ Output shorted for no more than one second. No more than one output shorted at a time.

⁽³⁾ This parameter is tested initially and after a design or process change that affects the parameter.

⁽⁴⁾ Latch-up protection is provided for stresses up to 100 mA on address and data pins from -1V to V_{CC} +1V.

INSTRUCTION SET

			Address		Data			
Instruction	Start Bit	Opcode	128 x 8	64 x 16	128 x 8	64 x 16	Comments	
READ	1	1 0	A6-A0	A5-A0			Read Address AN-A0	
ERASE	1	1 1	A6-A0	A5-A0			Clear Address AN-A0	
WRITE	1	0 1	A6-A0	A 5– A 0	D7-D0	D15-D0	Write Address AN-A0	
EWEN	1	0 0	11XXXXX	11XXXX			Write Enable	
EWDS	1	0 0	00XXXXX	00XXXX			Write Disable	
ERAL	1	0 0	10XXXXX	10XXXX			Clear All Addresses	
WRAL	1	0 0	01XXXXX	01XXXX	D7-D0	D15-D0	Write All Addresses	

A.C. CHARACTERISTICS

CAT32C101 T_A = 0°C to +70°C, V_{CC} = +2.2V to +3.5V , unless otherwise specified.

			Limits				
Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions	
tcss	CS Setup Time	200			ns		
tcsH	CS Hold Time	0			ns	C _L = 100pF	
tois	DI Setup Time	400			ns	V _{OL} = 0.3V	
tDIH	DI Hold Time	400			ns	V _{OH} = V _{CC} - 0.3	
t _{PD1}	Output Delay to 1			2	μѕ	V _{IL} = 0.3V	
t _{PD0}	Output Delay to 0			2	μs	V _{IH} = V _{CC} - 0.3	
t _{HZ} (3)	Output Delay to High-Z			400	ns		
tew	Program/Erase Pulse Width			20	ms		
tcsmin	Minimum CS Low Time	1			μs		
tskHi	Minimum SK High Time	1			μs		
tsklow	Minimum SK Low time	1			μs		
tsv	Output Delay to Status Valid			1	μs	C _L = 100pF	
SK _{MAX}	Maximum Clock Frequency	DC		250	kHz		

Note:

⁽³⁾ This parameter is tested initially and after a design or process change that affects the parameter.

DEVICE OPERATION

The CAT32C101 is a 1024 bit nonvolatile memory intended for use with industry standard microprocessors. The CAT32C101 can be organized as either 64 registers by 16 bits, or as 128 registers by 8 bits. Seven 9 bit instructions (10 bit instruction in 128 by 8 organization) control the reading, writing and erase operations of the device. The CAT32C101 operates on a single 2.2-3.5V supply and will generate on chip, the high voltage required during any write operation.

Instructions, addresses, and write data are clocked into the DI pin on the rising edge of the clock (SK). The DO pin is normally in a high impedance state except when reading data from the device, or when checking the ready/busy status after a write operation.

The ready/busy status can be determined after a write

operation by selecting the device (CS high) and polling the DO pin; DO low indicates that the write operation is not completed, while DO high indicates that the device is ready for the next instruction. If necessary, the DO pin may be placed back into a high impedance state during chip select by shifting a dummy "1" into the DI pin. The DO pin will enter the high impedance state on the falling edge of the clock (SK). Placing the DO pin into the high impedance state is recommended in applications where the DI pin and the DO pin are to be tied together to form a common DI/O pin.

The format for all instructions sent to the CAT32C101 is a logical "1" start bit, a 2 bit (or 4 bit) op code, a 6 bit address (7 bit address when organized as 128 x 8), and for write operations a 16 bit data field (8 bit data field when organized as 128 x 8).

Figure 1. Sychronous Data Timing (5)

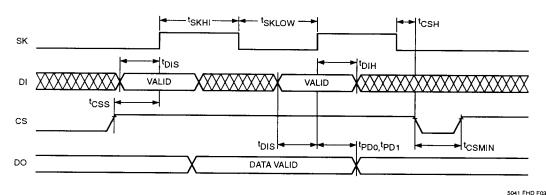
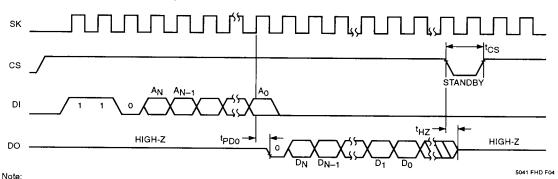


Figure 2. Read Instruction Timing (5)



(5) The ORG pin is used to configure the device for x8 or x16 operation. When x8 organization is selected, AN = A6 and DN = D7. When x16 organization is selected, AN = A5 and DN = D15.

At power-down, when V_{CC} falls below a threshold of approximately 1.7V, the data protection circuitry inhibits the erase and write instructions and a write disable (EWDS) is executed internally.

NOTE: This device will accept a start bit that is generated when both SK and DI are high with respect to a low to high transition of CS.

Read

Upon receiving a READ command and an address (clocked into the DI pin), the DO pin of the CAT32C101 will come out of the high impedance state and, after sending an initial dummy zero bit, will begin shifting out the data addressed. The output data bits will toggle on the rising edge of the SK clock and are stable after the specified time delay (tpD0 or tpD1).

Write

After receiving a WRITE command, address and the

data, the CS (chip select) pin must be deselected for a minimum of 1µs (tcsmin). The falling edge of CS will start the self clocking clear and data store cycle of the memory location specified in the instruction. The clocking of the SK pin is not necessary after the device has entered the self clocking mode. The ready/busy status of the CAT32C101 can be determined by selecting the device and polling the DO pin. Since this device features Auto-Clear before write, it is NOT necessary to erase a memory location before the WRITE command is sent.

Erase

Upon receiving an ERASE command and address, the CS (chip select) pin must be deselected for a minimum of 1µs (tcsmin). The falling edge of CS will start the self clocking clear cycle of the memory location specified in the instruction. The clocking of the SK pin is not necessary after the device has entered the self clocking mode. The ready/busy status of the CAT32C101 can be determined by selecting the device and polling the DO pin.



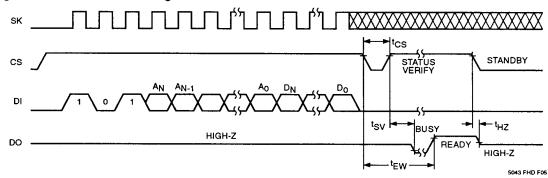
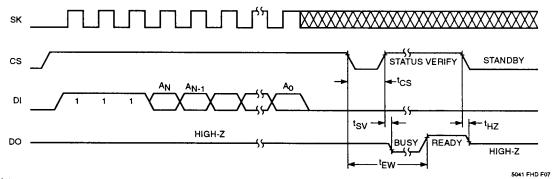


Figure 4. Erase Instruction Timing (5)



Note:

(5) The ORG pin is used to configure the device for x8 or x16 operation. When x8 organization is selected, AN = A6 and DN = D7. When x16 organization is selected, AN = A5 and DN = D15.

Once cleared, the content of a cleared location returns to a logical "1" state.

Erase/Write Enable and Disable

The CAT32C101 powers up in the write disable state. Any writing after power-up or after an EWDS (write disable) instruction must first be preceded by the EWEN (write enable) instruction. Once the write instruction is enabled, it will remain enabled until power to the device is removed, or the EWDS instruction is sent. The EWDS instruction can be used to disable all CAT32C101 write and clear instructions, and will prevent any accidental writing or clearing of the device. Data can be read normally from the device regardless of the write enable/ disable status.

Erase All

Upon receiving an ERAL command, the CS (chip select) pin must be deselected for a minimum of 1µs (tcsmin).

The falling edge of CS will start the self clocking clear cycle of all memory locations in the device. The clocking of the SK pin is not necessary after the device has entered the self clocking mode. The ready/busy status of the CAT32C101 can be determined by selecting the device and polling the DO pin. Once cleared, the contents of all memory bits return to a logical "1" state.

Write All

Upon receiving a WRAL command and data, the CS (chip select) pin must be deselected for a minimum of 1µs (tcsmin). The falling edge of CS will start the self clocking data write to all memory locations in the device. The clocking of the SK pin is not necessary after the device has entered the self clocking mode. The ready/busy status of the CAT32C101 can be determined by selecting the device and polling the DO pin. It IS necessary for all memory locations to be cleared before the WRAL command is executed.

Figure 5. EWEN/EWDS Instruction Timing (5)

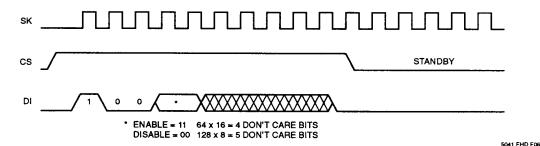
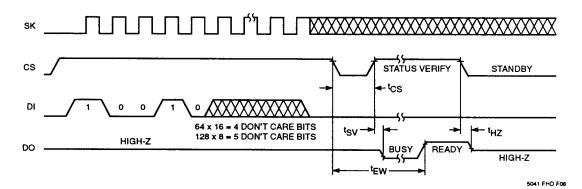


Figure 6. ERAL Instruction Timing (5)



Note

(5) The ORG pin is used to configure the device for x8 or x16 operation. When x8 organization is selected, AN = A6 and DN = D7. When x16 organization is selected, AN = A5 and DN = D15.

Start Bit Timing

The CAT32C101 features an alternate start bit timing where the device will accept a start bit that is generated when both SK and DI are high with respect to a low to high transition of CS (see Figure 8). This allows the user to

send instructions from microprocessors that transmit and receive data using a sequence of 8 clock cycles only. Once this start bit is generated all subsequent data is clocked into the device on the positive clock edge of SK.

Figure 7. WRAL Instruction Timing (5)

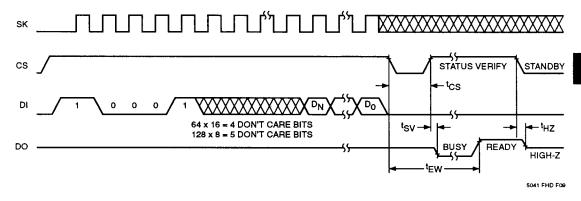
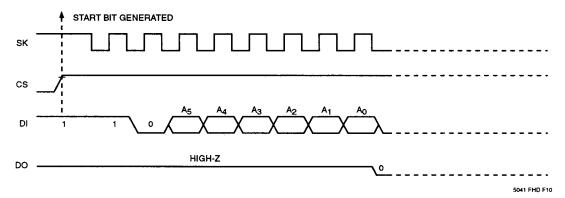


Figure 8. Alternate Start Bit Timing Example: Read Instruction (x 16) (5)



Note:

⁽⁵⁾ The ORG pin is used to configure the device for x8 or x16 operation. When x8 organization is selected, AN = A6 and DN = D7. When x16 organization is selected, AN = A5 and DN = D15.